

查询"2PD602AQL 供应表 2PD602AQL; 2PD602ARL; 2PD602ASL

50 V, 500 mA NPN general-purpose transistors

Rev. 01 — 27 October 2008

Product data sheet

Product profile 1.

1.1 General description

NPN general-purpose transistors in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview**

| Type number ^[1] | Package | PNP complement | |
|----------------------------|---------|----------------|--------------|
| | NXP | JEDEC | |
| 2PD602AQL | SOT23 | TO-236AB | - |
| 2PD602ARL | RL | | 2PB710ARL |
| 2PD602ASL | | | 2PB710ASL |
| 2PD602AQL/DG | SOT23 | TO-236AB | - |
| 2PD602ARL/DG | | 2PB710ARL/DG | |
| 2PD602ASL/DG | | | 2PB710ASL/DG |

[1] /DG: halogen-free

1.2 Features

- General-purpose transistors
- Three current gain selections
- AEC-Q101 qualified
- Small SMD plastic package

1.3 Applications

General-purpose switching and amplification

1.4 Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|---------------------------|------------|-----|-----|-----|------|
| V_{CEO} | collector-emitter voltage | open base | - | - | 50 | V |
| I _C | collector current | | - | - | 500 | mA |



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| Table 2. | Quick reference data . | continued | | | | |
|-----------------|-------------------------|--|------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| h _{FE} | DC current gain | V _{CE} = 10 V; I _C = 150 mA | <u>[1]</u> | | | |
| | h _{FE} group Q | | 85 | - | 170 | |
| | h _{FE} group R | | 120 | - | 240 | |
| | h _{FE} group S | | 170 | - | 340 | |
| | | | | | | |

2. Pinning information

| Table 3. | Pinning | | |
|----------|-------------|--------------------|----------------|
| Pin | Description | Simplified outline | Graphic symbol |
| 1 | base | — | _ |
| 2 | emitter | | 3 |
| 3 | collector | | 1-1-2 |
| | | | sym021 |

3. Ordering information

| Type number ^[1] | Package | | | | | |
|----------------------------|---------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| 2PD602AQL | - | plastic surface-mounted package; 3 leads | SOT23 | | | |
| 2PD602ARL | | | | | | |
| 2PD602ASL | | | | | | |
| 2PD602AQL/DG | - | plastic surface-mounted package; 3 leads | SOT23 | | | |
| 2PD602ARL/DG | | | | | | |
| 2PD602ASL/DG | | | | | | |

4. Marking

| Table 5. Marking codes | |
|------------------------|-----------------------------|
| Type number | Marking code ^[1] |
| 2PD602AQL | SH* |
| 2PD602ARL | SG* |
| 2PD602ASL | SF* |

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| Table 5. | Marking | codes | continued |
|----------|---------|-------|-----------|
|----------|---------|-------|-----------|

| Type number | Marking code ^[1] |
|--------------|-----------------------------|
| 2PD602AQL/DG | SX* |
| 2PD602ARL/DG | SW* |
| 2PD602ASL/DG | SV* |

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------------|--|--------------|------|------|
| V _{CBO} | collector-base voltage | open emitter | - | 60 | V |
| V _{CEO} | collector-emitter voltage | open base | - | 50 | V |
| V_{EBO} | emitter-base voltage | open collector | - | 5 | V |
| I _C | collector current | | - | 500 | mA |
| I _{CM} | peak collector current | single pulse; $t_p \leq 1 ms$ | - | 1 | A |
| I _{BM} | peak base current | single pulse; t _p ≤ 1 ms | - | 200 | mA |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | <u>[1]</u> _ | 250 | mW |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -55 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| | | | | | |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

| Table 7. | Thermal characteristics | | | | | |
|----------------------|---|-------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | <u>[1]</u> _ | - | 500 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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7. Characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------------------|--------------------------------------|---|------------|-----|-----|-----|------|
| I _{CBO} | collector-base cut-off current | $V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}$ | | - | - | 10 | nA |
| | | $V_{CB} = 60 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$ | | - | - | 5 | μA |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = 4 \text{ V}; \text{ I}_{C} = 0 \text{ A}$ | | - | - | 10 | nA |
| h _{FE} | DC current gain | $V_{CE} = 10 \text{ V};$ $I_{C} = 500 \text{ mA}$ | <u>[1]</u> | 40 | - | - | |
| | h _{FE} group Q | $V_{CE} = 10 \text{ V};$ $I_{C} = 150 \text{ mA}$ | <u>[1]</u> | 85 | - | 170 | |
| | h _{FE} group R | V _{CE} = 10 V; I _C = 150 mA | <u>[1]</u> | 120 | - | 240 | |
| | h _{FE} group S | V _{CE} = 10 V; I _C = 150 mA | <u>[1]</u> | 170 | - | 340 | |
| V _{CEsat} | collector-emitter saturation voltage | $I_{\rm C}$ = 300 mA; $I_{\rm B}$ = 30 mA | <u>[1]</u> | - | - | 600 | mV |
| f _T | transition frequency | $V_{CE} = 10 V;$ $I_{C} = 50 mA;$ f = 100 MHz | [1] | | | | |
| | h _{FE} group Q | | | 140 | - | - | MHz |
| | h _{FE} group R | | | 160 | - | - | MHz |
| | h _{FE} group S | | | 180 | - | - | MHz |
| C _c | collector capacitance | $V_{CB} = 10 V;$ $I_E = i_e = 0 A;$ f = 1 MHz | | - | - | 15 | pF |

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

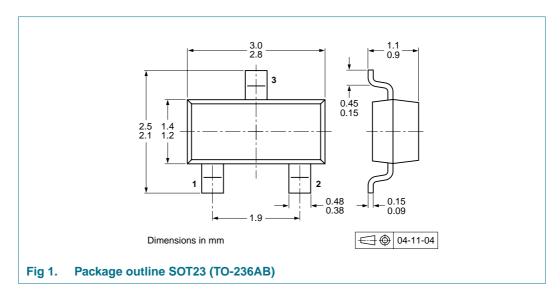
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number ^[2] | Package | Description | Packing | g quantity |
|----------------------------|---------|--------------------------------|---------|------------|
| | | | 3000 | 10000 |
| 2PD602AQL | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | -235 |
| 2PD602ARL | | | | |
| 2PD602ASL | | | | |
| 2PD602AQL/DG | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | -235 |
| 2PD602ARL/DG | | | | |
| 2PD602ASL/DG | | | | |

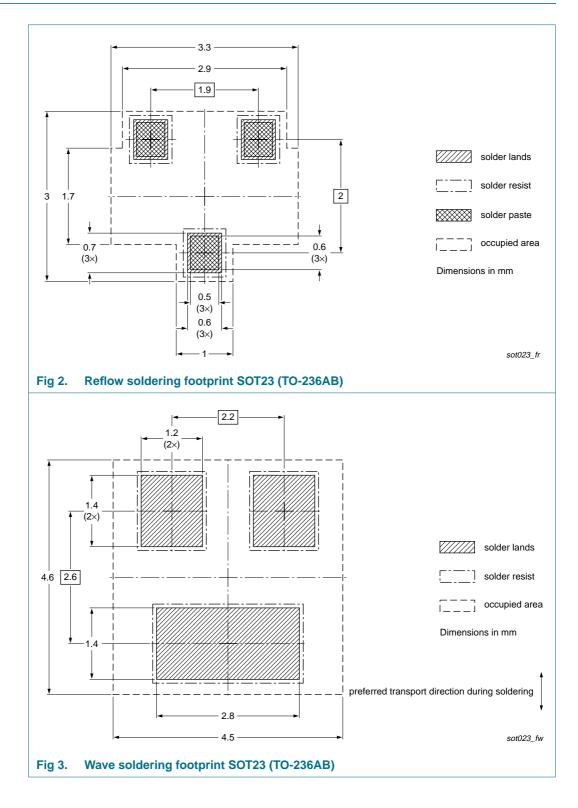
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] /DG: halogen-free

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11. Soldering



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12. Revision history

| Table 10. Revision history | | | | | |
|----------------------------|--------------|--------------------|---------------|------------|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
| 2PD602AXL_1 | 20081027 | Product data sheet | - | - | |

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13. Legal information

13.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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